

Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V	Steady State	$T_A = +25^{\circ}C$ (Note 6) $T_A = +70^{\circ}C$ (Note 6) $T_A = +25^{\circ}C$ (Note 5)	۱ _D	6.7 5.4 4.8	A
Maximum Body Diode Forward Current (Note 6)			ls	5.7	А
Pulsed Drain Current (Note 7)			I _{DM}	28.5	А
Pulsed Source Current (Note 7)			I _{SM}	28.5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation Linear Derating Factor	T _A = +25°C (Note 5)	PD	2 16	W mW/°C
Total Power Dissipation Linear Derating Factor	T _A = +25°C (Note 6)	PD	3.9 31	W mW/°C
Thermal Resistance, Junction to Ambient	Steady state (Note 5)	Devi	62.5	°C/W
merma Resistance, Junction to Ambient	Steady state (Note 6)	R _{θJA}	32	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	—	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)	-						
Gate Threshold Voltage	V _{GS(th)}	1.0	_	_	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance (Note 8)	Press	_	_	50	mΩ	$V_{GS} = 10V, I_D = 3.6A$	
	R _{DS(on)}	_	—	70	11122	$V_{GS} = 4.5V, I_D = 3.0A$	
Diode Forward Voltage (Note 8)	V _{SD}	_	0.85	0.95	V	$V_{GS} = 0V, I_{S} = 5.5A$	
Forward Transconductance (Note 8 & 10)	g fs	_	10.2	_	S	$V_{DS} = 15V, I_D = 4.5A$	
DYNAMIC CHARACTERISTICS (Note 10)			•	•	•		
Input Capacitance	Ciss	_	1,063	—	pF	$V_{DS} = 30V, V_{GS} = 0V$ f = 1.0MHz	
Output Capacitance	Coss	_	104	_			
Reverse Transfer Capacitance	C _{rss}	_	64	_			
Total Gate Charge (V _{GS} = 5.0V)	Qg	_	11	_		$V_{DS} = 30V, I_D = 1.4A,$	
Total Gate Charge (V _{GS} = 10V)	Qg		20.4	_	nC		
Gate-Source Charge	Qgs		4.1	_	nc		
Gate-Drain Charge	Q _{gd}	_	5.1	_			
Turn-On Delay Time	t _{D(on)}	_	3.8	_		$V_{GS} = 10V, V_{DD} = 30V, R_G = 6.0\Omega,$ $I_{D} = 1.0A$	
Turn-On Rise Time	tr	_	4.0				
Turn-Off Delay Time	t _{D(off)}		26.2		nS		
Turn-Off Fall Time	t _f		10.6				
Body Diode Reverse Recovery Time	t _{rr}		22		nS		
Body Diode Reverse Recovery Charge	Qrr		21.4	_	nC	I _F = 2.2A, dl/dt = 100A/μs	

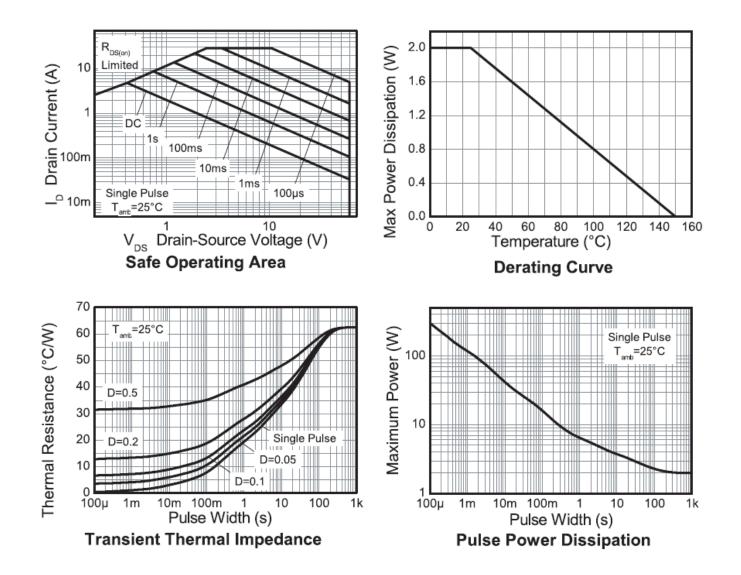
5. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions 6. For a device surface mounted on FR4 PCB measured at t \leq 10 secs. Notes:

Provide a standard to the standa

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

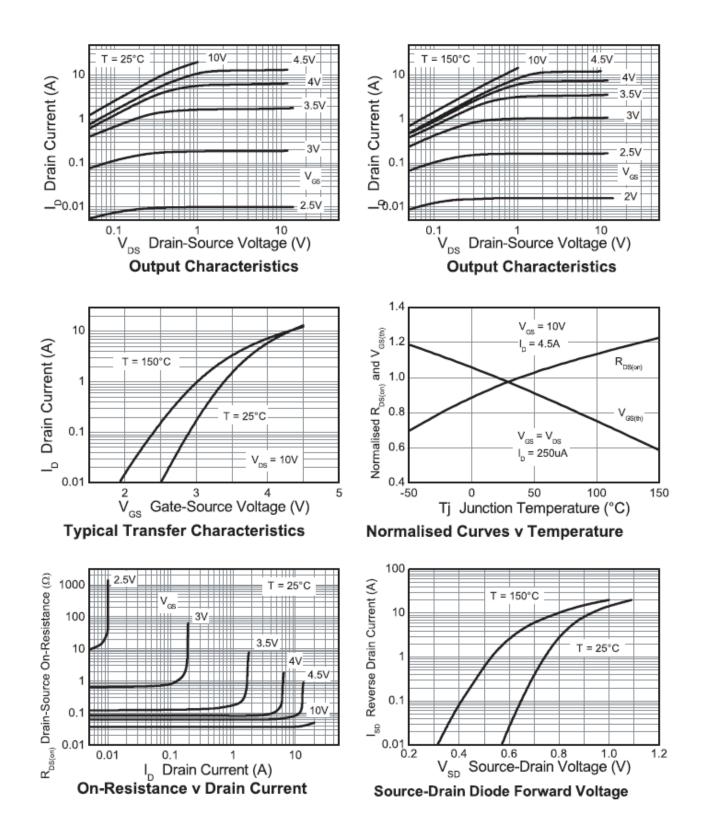


Typical Characteristics



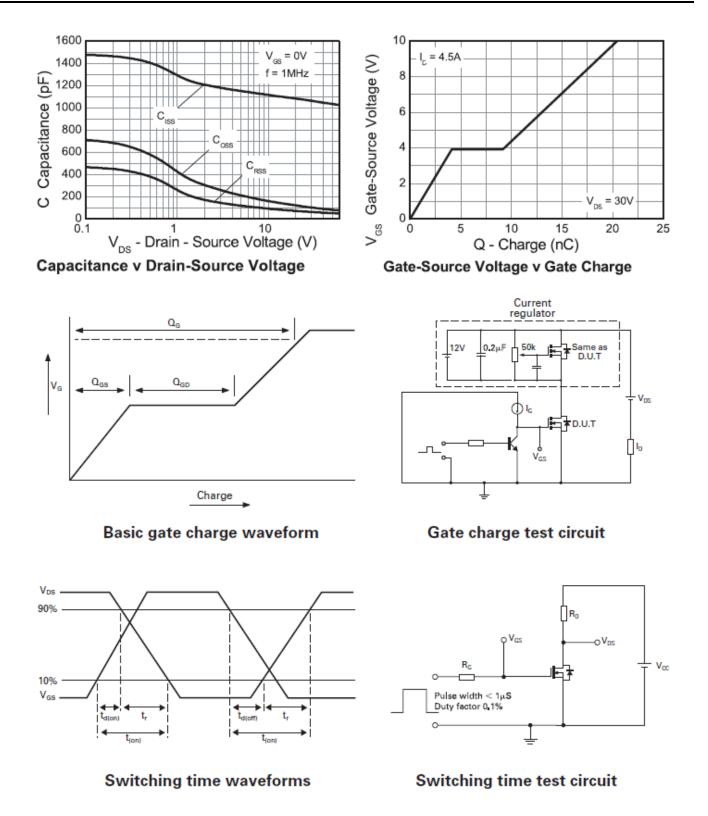


Typical Characteristics (continued)





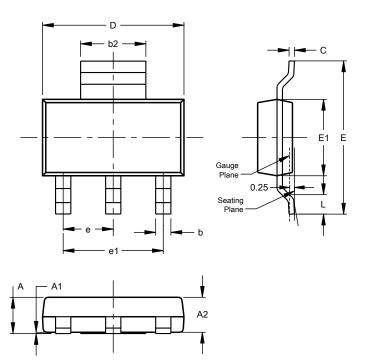
Typical Characteristics (continued)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



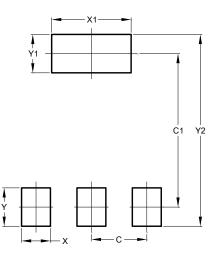
SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
c	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
e			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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